



HFZT

1SS181

Small Signal Switching Diodes

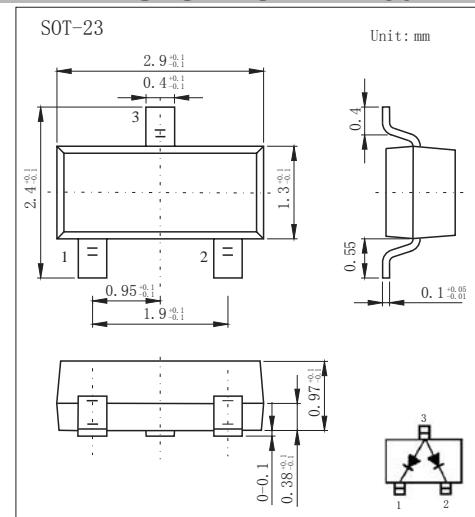
FEATURES

- Low forward voltage $V_F(3)=0.92V$ (typ).
- Fast switching.
- Fast reverse recovery time: $t_{rr}=1.6ns$ (typ)

MECHANICAL DATA

- Case: SOT-23 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any

**VOLTAGE RANGE: 85V
PEAK PULSE POWER:150mW**



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Characteristic	Symbol	Limits	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	85	V
DC Reverse Voltage	V_R	80	V
Forward current(max)	I_{FM}	300	mA
Surge current (10ms)	I_{FSM}	2	A
Forward Output current	I_o	100	mA
Power Dissipation	P_d	150	mW
Operating Junction Temperature Range	T_j	125	°C
Storage Temperature Range	T_{STG}	-55 to +125	°C

Electrical Specification ($T_A=25^\circ C$ unless otherwise specified)

Characteristic	Symbol	Min	Typ	MAX	UNIT	Test Condition
Reverse Breakdown Voltage	$V(BR)R$	80	-	-	V	$I_R= 100\mu A$
Forward Voltage	V_F	-	0.61 0.74 0.92	1.2	V	$I_F=1mA$ $I_F=10mA$ $I_F=100mA$
Reverse Leakage Current	I_R	-		0.1 0.5	μA	$VR=30V$ $VR=80V$
Total Capacitance	C_T	-	2.2	4.0	pF	$VR=0V, f=1.0MHz$
Reverse Recovery Time	t_{rr}	-	1.6	4.0	ns	$I_F=I_R=10mA I_{rr}=0.1*I_R$

Marking: A3

RATINGS AND CHARACTERISTIC CURVES

